Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Ceramic

Function For Which Designed:

Impatt diode

End Application:

An/apm-427

Features Provided:

Hermetically sealed case

Semiconductor Material:

Gallium arsenide

Voltage Rating In Volts Per Characteristic:

23.0 breakdown voltage, instantaneous

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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